SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 872, REV. E Formerly SHD1262 / P / N / D

HERMETIC POWER SCHOTTKY RECTIFIER

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

MAXIMUM RATINGS

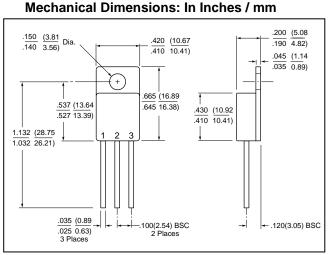
ALL RATINGS ARE AT $T_{\rm A}$ = 25 °C UNLESS OTHERWISE SPECIFIED.

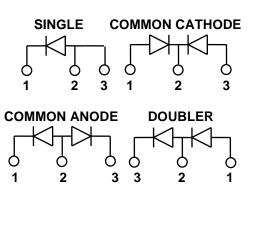
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE (PER LEG)	PIV	45	Volts
Max. Average Forward Current, 50% duty cycle, rectangular wave form (Single/Doubler)	I _{F(AV)}	15	Amps
Max. Average Forward Current, 50% duty cycle, rectangular wave form (Common Cathode/Common Anode) I _{F(AV)}	IF(AV)	30	Amps
PEAK SINGLE CYCLE SURGE CURRENT $t_p = 8.3$ msec. (PER LEG)	IFSM	150	Amps
MAXIMUM THERMAL RESISTANCE (Single)	Rejc	2.82	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	T _{op} , T _{stg}	-65 to +175	°C

ELECTRICAL CHARACTERISTICS

CHARACTERISTICS	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP Per Leg			
$I_F = 15A, T_A = 25 \ ^{0}C$	Vf	0.78	Volts
I _F = 15A,T _A = 125 ^o C		0.71	
MAXIMUM REVERSE CURRENT I _r @ PIV (PER LEG) $T_A = 25 \ ^{\circ}C$	l _r	2	mA
T _A = 125 ^o C		20	mA
JUNCTION CAPACITANCE $V_R = 5Vdc, f = 1mHz$	CJ	800	pF
$V_{SIG} = 50 \text{mV} (p-p) (Max) (PER LEG)$			

SENSITRON TECHNICAL DATA DATA SHEET 872, REV. E





TO-257

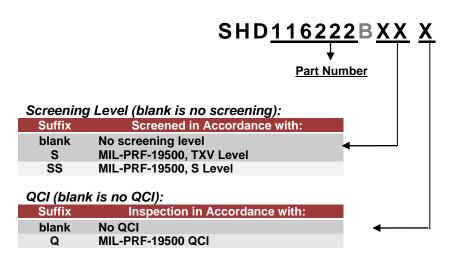
PINOUT TABLE

(Curves are for bare die only. SD125SB45A)

SENSITRON

TECHNICAL DATA DATA SHEET 872, REV.E

PART ORDERING INFORMATION:



DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the Sensitron Semiconductor sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall Sensitron Semiconductor be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). Sensitron Semiconductor assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall Sensitron Semiconductor be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or Sensitron Semiconductor.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of Sensitron Semiconductor.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.